

SGM321/SGM358/SGM324 1MHz, 60µA, Rail-to-Rail I/O CMOS Operational Amplifiers

GENERAL DESCRIPTION

The SGM321 (single), SGM358 (dual) and SGM324 (quad) are low cost, voltage feedback amplifiers. These devices can operate from 2.1V to 5.5V single supply, and consume only 60µA quiescent current per amplifier. They provide rail-to-rail input with a wide input common mode voltage range and rail-to-rail output voltage swing. This feature makes SGM321/358/324 appropriate for buffering ASIC.

The SGM321/358/324 offer a gain-bandwidth product of 1MHz and an ultra-low input bias current of 10pA. They are well suited for piezoelectric sensors, integrators and photodiode amplifiers.

The SGM321/358/324 are designed into a wide range of applications, such as battery-powered instrumentation, safety monitoring, portable systems, and transducer interface circuits in low power systems.

The SGM321 is available in Green SOT-23-5 and SC70-5 packages. The SGM358 is available in Green SOIC-8, MSOP-8 and DIP-8 packages. The SGM324 is available in Green TSSOP-14 and SOIC-14 packages. They are specified over the extended industrial temperature range (-40°C to +85°C).

FEATURES

- Low Cost
- Input Offset Voltage: 5mV (MAX)
- Ultra-Low Input Bias Current: 10pA (TYP)
- Unity-Gain Stable
- Gain-Bandwidth Product: 1MHz
- Rail-to-Rail Input and Output
- Supply Voltage Range: 2.1V to 5.5V
- Input Voltage Range:
 - -0.1V to 5.6V with $V_S = 5.5V$
- Low Quiescent Current: 60µA/Amplifier (TYP)
- -40°C to +85°C Operating Temperature Range
- Small Packaging:
 - SGM321 Available in Green SOT-23-5 and
 - SC70-5 Packages
 - SGM358 Available in Green SOIC-8, MSOP-8 and
 - **DIP-8 Packages**
 - SGM324 Available in Green SOIC-14 and
 - **TSSOP-14 Packages**

APPLICATIONS

ASIC Input or Output Amplifiers

Piezoelectric Transducer Amplifiers

Battery-Powered Equipment

Portable Equipment

Sensor Interfaces

Medical Instrumentation

Mobile Communications

Audio Outputs

Smoke Detectors

Mobile Telephones

Notebook PCs

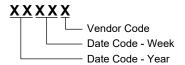
PCMCIA Cards

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
	SC70-5	-40°C to +85°C	SGM321YC5/TR	321	Tape and Reel, 3000
SGM321	SOT-23-5	-40°C to +85°C	SGM321YN5/TR	321	Tape and Reel, 3000
SOT-23-5		-40°C to +85°C	SGM321BYN5/TR	321B	Tape and Reel, 3000
	SOIC-8	-40°C to +85°C	SGM358YS/TR	SGM358YS XXXXX	Tape and Reel, 4000
SGM358	MSOP-8	-40°C to +85°C	SGM358YMS/TR	SGM358 YMS XXXXX	Tape and Reel, 3000
	DIP-8	-40°C to +85°C	SGM358YP	SGM358YP XXXXX	20 Tube (1000pcs)
	SOIC-14	-40°C to +85°C	SGM324YS14/TR	SGM324YS14 XXXXX	Tape and Reel, 2500
SGM324	TSSOP-14	-40°C to +85°C	SGM324YTS14/TR	SGM324 YTS14 XXXXX	Tape and Reel, 3000

MARKING INFORMATION

NOTE: XXXXX = Date Code and Vendor Code.



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, +V _S to -V _S	6V
Input Common Mode Voltage Range	
(-V _S) - 0.3	$3V \text{ to } (+V_S) + 0.3V$
Package Thermal Resistance @ T _A = +25°	C
SC70-5, θ _{JA}	333°C/W
SOT-23-5, θ _{JA}	190°C/W
SOIC-8, θ _{JA}	125°C/W
MSOP-8, θ _{JA}	216°C/W
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
HBM	4000V
MM	400V

RECOMMENDED OPERATING CONDITIONS

Operating Temperature Range-40°C to +85°C

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

ESD SENSITIVITY CAUTION

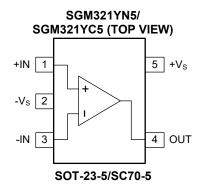
This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

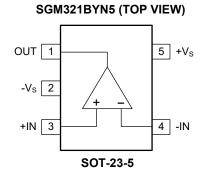
DISCLAIMER

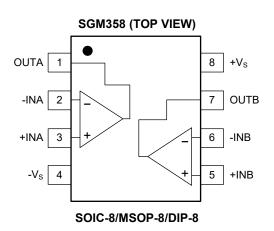
SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

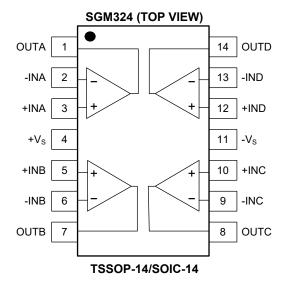


PIN CONFIGURATIONS









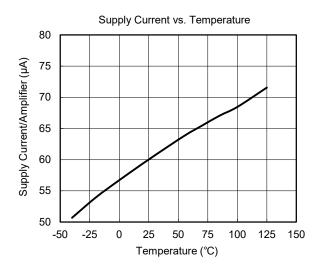
ELECTRICAL CHARACTERISTICS

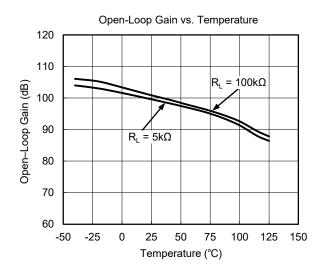
(At V_S = 5V, R_L = 100k Ω connected to $V_S/2$, and V_{OUT} = $V_S/2$, unless otherwise noted.)

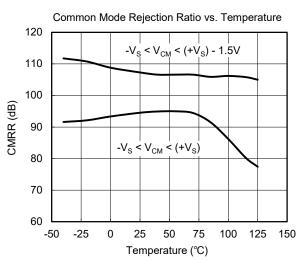
			SGM321/358/324				
	0)44501	CONDITIONS	TYP	MIN/M	IAX OVER	TEMPERA	TURE
PARAMETER	SYMBOL	CONDITIONS	+25°C	+25°C	-40°C to +85°C	UNITS	MIN/MAX
Input Characteristics							
Input Offset Voltage	Vos	$V_{CM} = V_S/2$	0.8	5	5.6	mV	MAX
Input Bias Current	I _B		10			pА	TYP
Input Offset Current	Ios		10			pА	TYP
Input Common Mode Voltage Range	V _{CM}	V _S = 5.5V	-0.1 to 5.6			V	TYP
Common Mode Pointion Patio	CMRR	$V_S = 5.5V$, $V_{CM} = -0.1V$ to 4V	70	62	62	4D	MINI
Common Mode Rejection Ratio	CIVIRR	$V_S = 5.5V$, $V_{CM} = -0.1V$ to $5.6V$	68	56	55	dB	MIN
Open Leen Veltage Cain	^	$R_L = 5k\Omega$, $V_{OUT} = 0.1V$ to 4.9V	80	70	70	٩D	MINI
Open-Loop Voltage Gain	A _{OL}	R_L = 100k Ω , V_{OUT} = 0.035V to 4.965V	84	80	80	dB	MIN
Input Offset Voltage Drift	ΔV _{OS} /ΔΤ		2.7			μV/°C	TYP
Output Characteristics							
Output Voltage Swing from Rail	V _{OH}	$R_L = 100 k\Omega$	4.997	4.980	4.970	V	MIN
	V _{OL}	$R_L = 100 k\Omega$	5	20	30	mV	MAX
	V _{OH}	$R_L = 10k\Omega$	4.992	4.970	4.960	V	MIN
	V _{OL}	$R_L = 10k\Omega$	8	30	40	mV	MAX
Outrout Command	I _{SOURCE}	D = 400 to 1/ /0	84	60	45		MIN
Output Current	I _{SINK}	$R_L = 10\Omega$ to $V_S/2$	75	60	45	mA	
Power Supply	•		1		•	•	•
Ou and the service Dance				2.1	2.5	V	MIN
Operating Voltage Range				5.5	5.5	V	MAX
Power Supply Rejection Ratio	PSRR	$V_S = 2.5V$ to 5.5V, $V_{CM} = 0.5V$	82	60	58	dB	MIN
Quiescent Current/Amplifier	ΙQ		60	80	86	μΑ	MAX
Dynamic Performance (C _L = 100p	oF)		1		•	•	•
Gain-Bandwidth Product	GBP		1			MHz	TYP
Slew Rate	SR	G = +1, 2V output step	0.52			V/µs	TYP
Settling Time to 0.1%	ts	G = +1, 2V output step	5.3			μs	TYP
Overload Recovery Time		$V_{IN} \cdot G = V_S$	2.6			μs	TYP
Noise Performance			•		•	•	•
Jamest Volta na Naisa Danaii	_	f = 1kHz	27			nV/ _{√Hz}	TYP
Input Voltage Noise Density	e _n	f = 10kHz	20			nV/ _{√Hz}	TYP

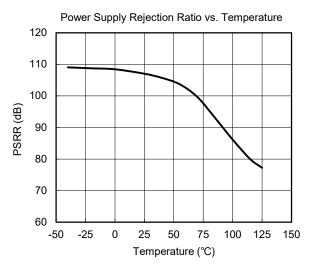
TYPICAL PERFORMANCE CHARACTERISTICS

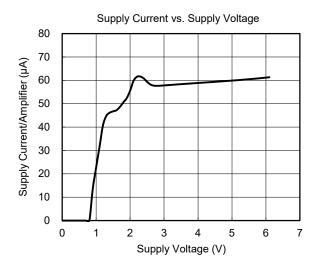
At T_A = +25°C, V_S = 5V, and R_L = 100k Ω connected to $V_S/2$, unless otherwise noted.

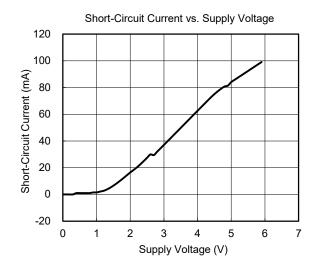






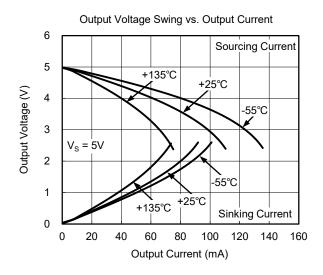


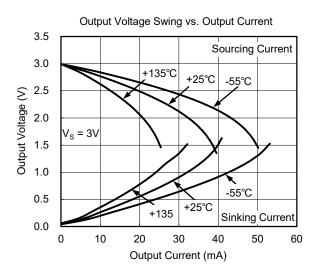


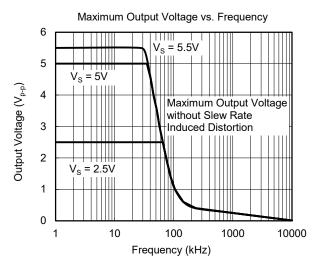


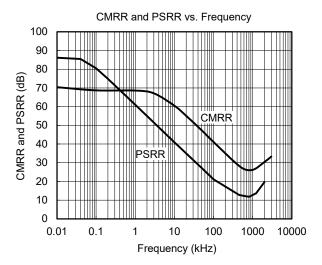
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

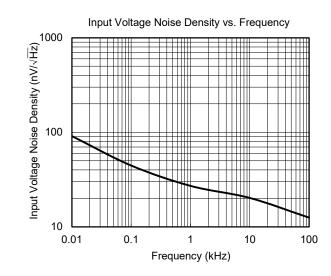
At T_A = +25°C, V_S = 5V, and R_L = 100k Ω connected to $V_S/2$, unless otherwise noted.

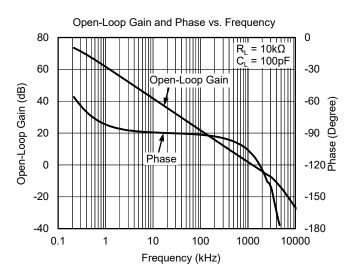






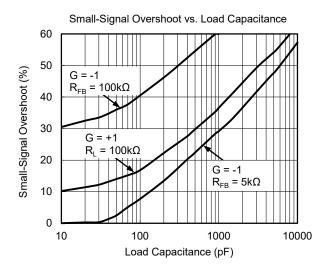


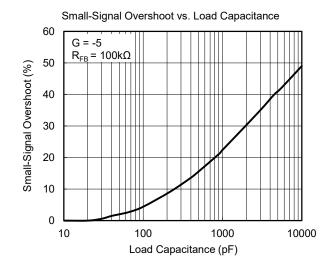


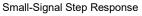


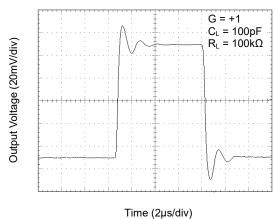
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

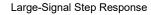
At T_A = +25°C, V_S = 5V, and R_L = 100k Ω connected to $V_S/2$, unless otherwise noted.

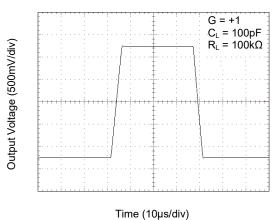




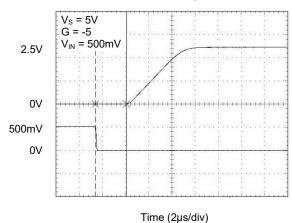








Overload Recovery Time



APPLICATION INFORMATION

Rail-to-Rail Input

When SGM321/SGM358/SGM324 work at the power supply between 2.1V and 5.5V, the input common mode voltage range is from (-V_S) - 0.1V to (+V_S) + 0.1V. In Figure 1, the ESD diodes between the inputs and the power supply rails will clamp the input voltage not to exceed the rails.

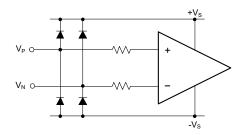


Figure 1. Input Equivalent Circuit

Rail-to-Rail Output

The SGM321/SGM358/SGM324 support rail-to-rail output operation. In single power supply application, for example, when +V $_{\rm S}$ = 5V, -V $_{\rm S}$ = GND, 100k Ω load resistor is tied from OUT pin to V $_{\rm S}/2$, the typical output swing range is from 0.005V to 4.997V.

Driving Capacitive Loads

The SGM321/SGM358/SGM324 are designed for driving the 250pF capacitive load with unity-gain stable. If greater capacitive load must be driven in application, the circuit in Figure 2 can be used. In this circuit, the IR drop voltage generated by $R_{\rm ISO}$ is compensated by feedback loop.

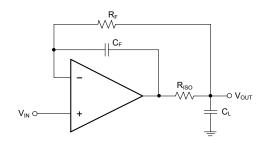


Figure 2. Circuit to Drive Heavy Capacitive Load

Power Supply Decoupling and Layout

A clean and low noise power supply is very important in amplifier circuit design, besides of input signal noise, the power supply is one of important source of noise to the amplifiers through $+V_S$ and $-V_S$ pins. Power supply bypassing is an effective method to clear up the noise at power supply, and the low impedance path to ground of decoupling capacitor will bypass the noise to GND. In application, $10\mu F$ ceramic capacitor paralleled with $0.1\mu F$ or $0.01\mu F$ ceramic capacitor is used in Figure 3. The ceramic capacitors should be placed as close as possible to $+V_S$ and $-V_S$ power supply pins.

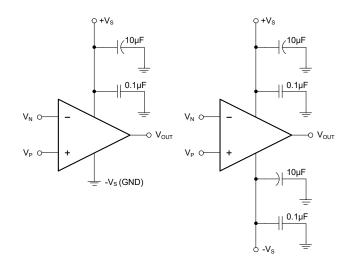


Figure 3. Amplifier Power Supply Bypassing

APPLICATION INFORMATION (continued)

Typical Application Circuits

Difference Amplifier

The circuit in Figure 4 is a design example of classical difference amplifier. If $R_4/R_3 = R_2/R_1$, then $V_{OUT} = (V_P - V_N) \times R_2/R_1 + V_{REF}$.

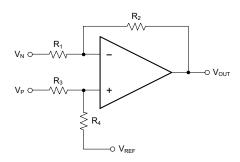


Figure 4. Difference Amplifier

High Input Impedance Difference Amplifier

The circuit in Figure 5 is a design example of high input impedance difference amplifier, the added amplifiers at the input are used to increase the input impedance and eliminate drawback of low input impedance in Figure 4.

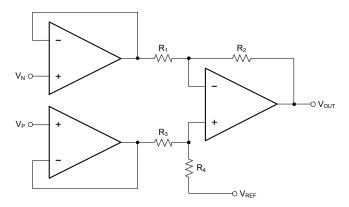


Figure 5. High Input Impedance Difference Amplifier

Active Low-Pass Filter

The circuit in Figure 6 is a design example of active low-pass filter, the DC gain is equal to $-R_2/R_1$ and the -3dB corner frequency is equal to $1/2\pi R_2C$. In this design, the filter bandwidth must be less than the bandwidth of the amplifier, the resistor values must be selected as low as possible to reduce ringing or oscillation generated by the parasitic parameters in PCB layout.

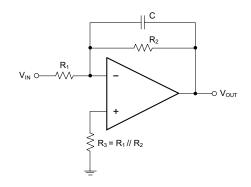


Figure 6. Active Low-Pass Filter

1MHz, 60µA, Rail-to-Rail I/O CMOS Operational Amplifiers

SGM321/SGM358/SGM324

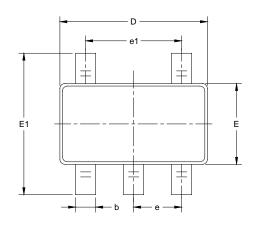
REVISION HISTORY

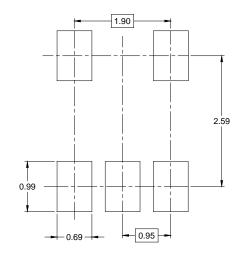
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

JULY 2023 – REV.E.2 to REV.E.3	Page
Updated Package Outline Dimensions section	12
APRIL 2019 – REV.E.1 to REV.E.2	Page
Added Open-Loop Gain and Phase vs. Frequency	6
MARCH 2017 – REV.E to REV.E.1	Page
Updated Package/Ordering Information section	2
NOVEMBER 2015 – REV.D.4 to REV.E	Page
Updated Packing Option of DIP-8	
Updated SOIC-14 and TSSOP-14 packages	14, 15
JANUARY 2013 – REV.D.3 to REV.D.4	Page
Added Tape and Reel Information section	16, 17

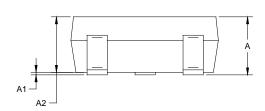


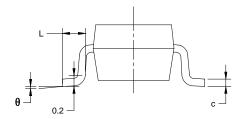
PACKAGE OUTLINE DIMENSIONS SOT-23-5





RECOMMENDED LAND PATTERN (Unit: mm)





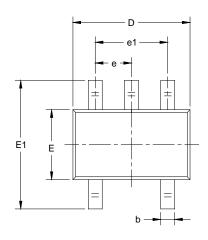
Symbol		nsions meters	Dimensions In Inches		
	MIN	MAX	MIN	MAX	
А	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
Е	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
е	0.950	BSC	0.037 BSC		
e1	1.900 BSC		0.075	BSC	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

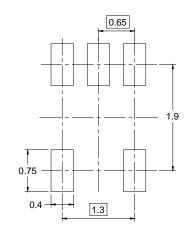
NOTES:

- 1. Body dimensions do not include mode flash or protrusion.
- 2. This drawing is subject to change without notice.

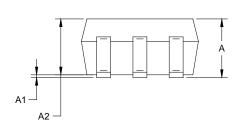


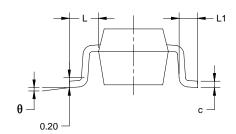
PACKAGE OUTLINE DIMENSIONS SC70-5





RECOMMENDED LAND PATTERN (Unit: mm)

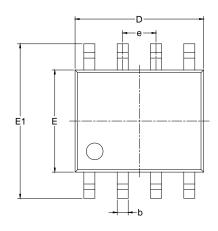


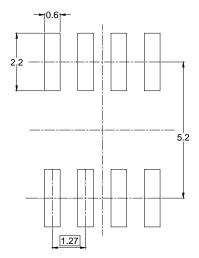


Symbol		nsions meters	Dimensions In Inches		
	MIN	MAX	MIN	MAX	
Α	0.800	1.100	0.031	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.800	1.000	0.031	0.039	
b	0.150	0.350	0.006	0.014	
С	0.080	0.220	0.003	0.009	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.65	TYP	0.026 TYP		
e1	1.300	BSC	0.051 BSC		
L	0.525	0.525 REF		REF	
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

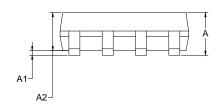
- Body dimensions do not include mode flash or protrusion.
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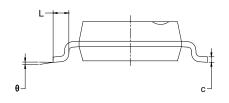
PACKAGE OUTLINE DIMENSIONS SOIC-8





RECOMMENDED LAND PATTERN (Unit: mm)

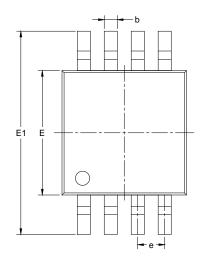


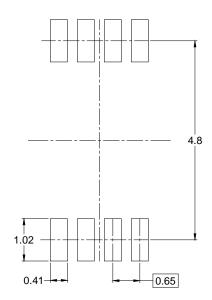


Symbol		nsions meters	Dimensions In Inches		
	MIN	MAX	MIN	MAX	
А	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
Е	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.27 BSC		0.050	BSC	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	

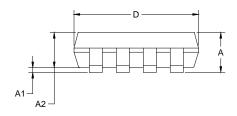
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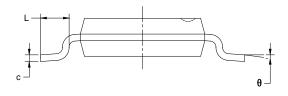
PACKAGE OUTLINE DIMENSIONS MSOP-8





RECOMMENDED LAND PATTERN (Unit: mm)

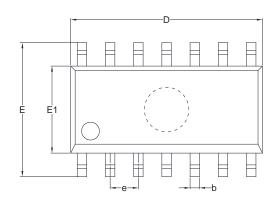


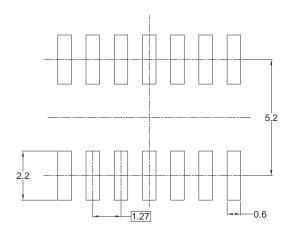


Symbol		nsions meters	Dimer In In	
	MIN	MAX	MIN	MAX
Α	0.820	1.100	0.032	0.043
A1	0.020	0.150	0.001	0.006
A2	0.750	0.950	0.030	0.037
b	0.250	0.380	0.010	0.015
С	0.090	0.230	0.004	0.009
D	2.900	3.100	0.114	0.122
E	2.900	3.100	0.114	0.122
E1	4.750	5.050	0.187	0.199
е	0.650 BSC		0.026	BSC
L	0.400	0.800	0.016	0.031
θ	0°	6°	0°	6°

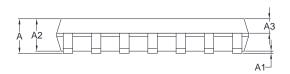
- Body dimensions do not include mode flash or protrusion.
 This drawing is subject to change without notice.

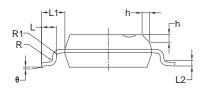
PACKAGE OUTLINE DIMENSIONS SOIC-14





RECOMMENDED LAND PATTERN (Unit: mm)





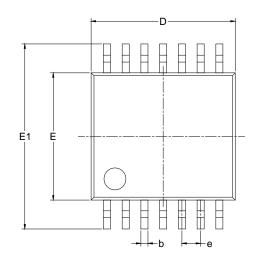
Symbol	_	nsions imeters		nsions ches	
	MIN	MAX	MIN	MAX	
Α	1.35	1.75	0.053	0.069	
A1	0.10	0.25	0.004	0.010	
A2	1.25	1.65	0.049	0.065	
A3	0.55	0.75	0.022	0.030	
b	0.36	0.49	0.014	0.019	
D	8.53	8.73	0.336	0.344	
Е	5.80	6.20	0.228	0.244	
E1	3.80	4.00	0.150	0.157	
е	1.27	BSC	0.050 BSC		
L	0.45	0.80	0.018	0.032	
L1	1.04	REF	0.040 REF		
L2	0.25	BSC	0.01 BSC		
R	0.07		0.003		
R1	0.07		0.003		
h	0.30	0.50	0.012	0.020	
θ	0°	8°	0°	8°	

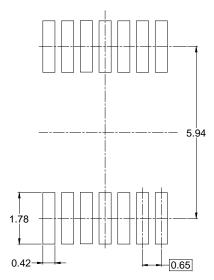
NOTES

- 1. Body dimensions do not include mode flash or protrusion.
- 2. This drawing is subject to change without notice.

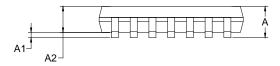


PACKAGE OUTLINE DIMENSIONS TSSOP-14





RECOMMENDED LAND PATTERN (Unit: mm)

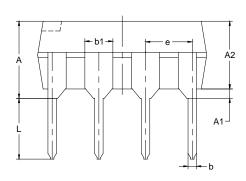


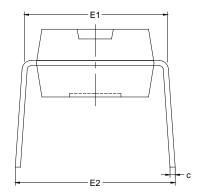


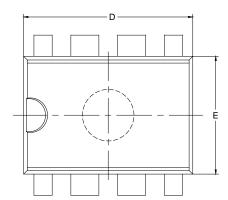
Symbol		nsions imeters	Dimer In In	nsions ches
	MIN	MAX	MIN	MAX
А		1.200		0.047
A1	0.050	0.150	0.002	0.006
A2	0.800	1.050	0.031	0.041
b	0.190	0.300	0.007	0.012
С	0.090	0.200	0.004	0.008
D	4.860	5.100	0.191	0.201
E	4.300	4.500	0.169	0.177
E1	6.250	6.550	0.246	0.258
е	0.650) BSC	0.026 BSC	
L	0.500	0.700	0.02	0.028
Н	0.25 TYP		0.01	TYP
θ	1°	7°	1°	7°

- Body dimensions do not include mode flash or protrusion.
 This drawing is subject to change without notice.

PACKAGE OUTLINE DIMENSIONS DIP-8







Symbol	-	nsions meters	Dimensions In Inches		
	MIN	MAX	MIN	MAX	
Α	3.710	4.310	0.146	0.170	
A1	0.510		0.020		
A2	3.200	3.600	0.126	0.142	
b	0.380	0.570	0.015	0.022	
b1	1.524	BSC	0.060 BSC		
С	0.204	0.360	0.008	0.014	
D	9.000	9.400	0.354	0.370	
E	6.200	6.600	0.244	0.260	
E1	7.320	7.920	0.288	0.312	
е	2.540 BSC		0.100 BSC		
L	3.000	3.600	0.118	0.142	
E2	8.400	9.000	0.331	0.354	

- NOTES:

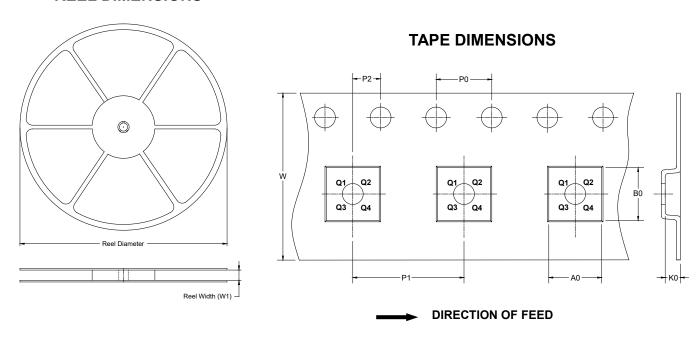
 1. Body dimensions do not include mode flash or protrusion.

 2. This drawing is subject to change without notice.



TAPE AND REEL INFORMATION

REEL DIMENSIONS

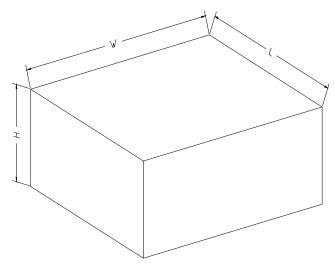


NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOT-23-5	7"	9.5	3.20	3.20	1.40	4.0	4.0	2.0	8.0	Q3
SC70-5	7"	9.5	2.40	2.50	1.20	4.0	4.0	2.0	8.0	Q3
SOIC-8	13"	12.4	6.40	5.40	2.10	4.0	8.0	2.0	12.0	Q1
MSOP-8	13"	12.4	5.20	3.30	1.50	4.0	8.0	2.0	12.0	Q1
SOIC-14	13"	16.4	6.60	9.30	2.10	4.0	8.0	2.0	16.0	Q1
TSSOP-14	13"	12.4	6.40	5.40	1.50	4.0	8.0	2.0	12.0	Q1

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18
13"	386	280	370	5